



# N-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ.)		
20	0.020 at V <sub>GS</sub> = 4.5 V	6.5	10		
	0.025 at V <sub>GS</sub> = 2.5 V	4.6	10		

### **FEATURES**

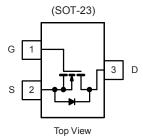
• DT-Trench Power MOSFET

### **APPLICATIONS**

- · Load Switching for Portable Devices
- DC/DC Converter



ROHS



ABSOLUTE MAXIMUM RATINGS (	T <sub>A</sub> = 25 °C, unle	ess otherwise	noted)			
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	20		V	
Gate-Source Voltage		$V_{GS}$	± 8			
Continuous Drain Comment /T = 450 °C\3	T <sub>A</sub> = 25 °C	I <sub>D</sub>	6.5	4.6	•	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		5.2	3.1		
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	30		Α	
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	0.92	0.7		
D	T <sub>A</sub> = 25 °C	P <sub>D</sub>	1.46	0.85	W	
Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		0.95	0.57	VV	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manipular lungtion to Aughient	t ≤ 5 s	R <sub>thJA</sub>	70	95	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		100	125	
Maximum Junction-to-Foot	Steady State	$R_{thJF}$	62	78	

#### Notes:

- a. Surface mounted on 1" x 1" FR4 board.
- b. Pulse width limited by maximum junction temperature.



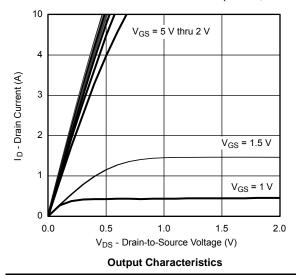
	Symbol		Limits				
Parameter		Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS}$ = 0 V, $I_D$ = 250 $\mu A$	20			<b>V</b>	
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	0.40		1.5	V	
Gate-Body Leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 8 V			± 100	nA	
		V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V			0.1	μΑ	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 50 °C			4		
		V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 70 °C			15		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 10 \text{ V}, V_{GS} = 4.5 \text{ V}$	30			Α	
5 . 6 . 6 3	В	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 2.6 A		0.020	0.022	Ω	
Drain-Source On-Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 1.6 A		0.025	0.027		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 5 V, I <sub>D</sub> = 3.6 A		13		S	
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> = 0.95 A, V <sub>GS</sub> = 0 V		0.7	1.2	V	
Dynamic <sup>b</sup>			1		•		
Total Gate Charge	$Q_g$			3.5	5.5		
Gate-Source Charge	$Q_{gs}$	$V_{DS}$ = 10 V, $V_{GS}$ = 4.5 V, $I_{D}$ = 3.6 A		0.6		nC	
Gate-Drain Charge	Q <sub>gd</sub>			0.45			
Gate Resistance	$R_g$	f = 1 MHz	2	4	8	Ω	
Switching			•				
Turn-On Delay Time	t <sub>d(on)</sub>			8	15		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 2.78 $\Omega$		7	15		
Turn-Off Delay Time	$t_{d(off)}$ $I_D \cong 3.6 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1$			30	45	ns	
Fall Time	t <sub>f</sub>			7	15		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	L = 2.6 A dl/dt = 100 A/···		8.5	15		
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	$I_F = 3.6 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		2	4	nC	

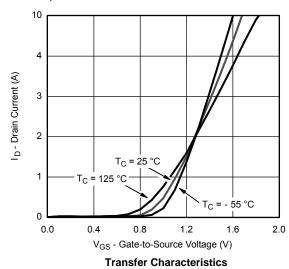
### Notes:

- a. Pulse test: Pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

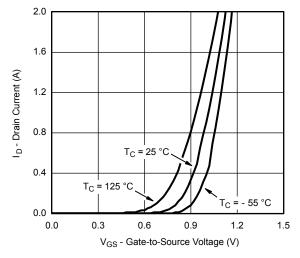
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



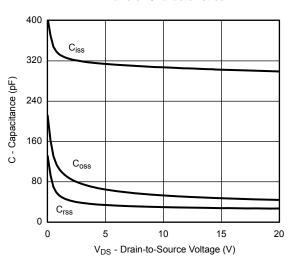




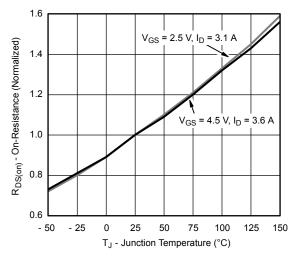
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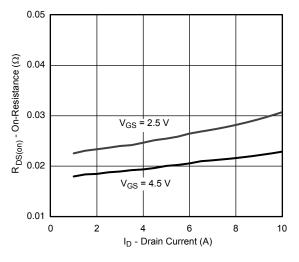
#### **Transfer Characteristics**



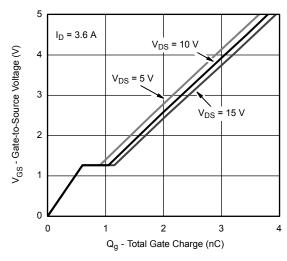
#### Capacitance



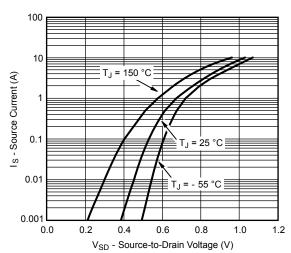
On-Resistance vs. Junction Temperature



On-Resistance vs. Drain Current



Gate Charge

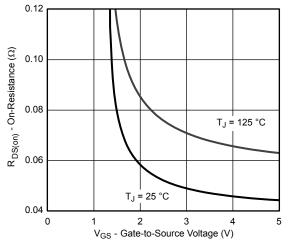


Source-Drain Diode Forward Voltage

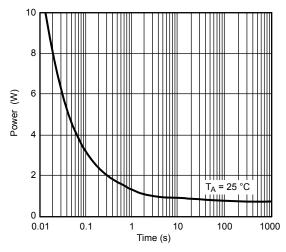




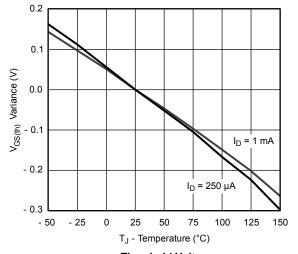
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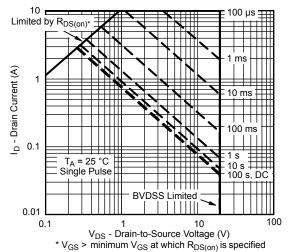
### On-Resistance vs. Gate-to-Source Voltage



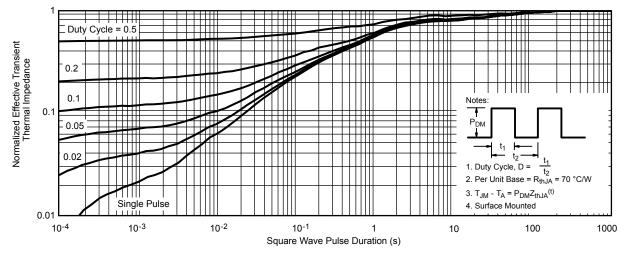
Single Pulse Power



Threshold Voltage



Safe Operating Area, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient





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